

## SCOPE: LOW POWER, MONOLITHIC, CMOS ANALOG MULTIPLEXER

<u>Device Type</u>	<u>Generic Number</u>	<u>Circuit Function</u>
01	MX7501S(x)/883B	8-Channel Analog Multiplexer
02	MX7502S(x)/883B	Differential 4-Channel Analog Multiplexer
03	MX7503S(x)/883B	8-Channel Analog Multiplexer, enable logic is inverted

Case Outline(s). The case outlines shall be designated in Mil-Std-1835 and as follows:

<u>Outline Letter</u>	<u>Mil-Std-1835</u>	<u>Case Outline</u>	<u>Package Code</u>
Q	GDIP1-T16 or CDIP2-T16	16 LEAD CERDIP	J16
E	CQCC1-N20	20-Pin Ceramic LCC	L20

### Absolute Maximum Ratings 2/

Voltage Referenced to V<sup>-</sup>

V<sup>+</sup> to GND ..... +18V  
V<sup>-</sup> to GND ..... -18V

V Between Any Switch Terminals 1/ ..... 25V

Digital Input Voltage Range..... V<sup>+</sup> to GND

Max Overtoltage at VOUT (V<sub>S</sub>) ..... V<sup>-</sup>, V<sup>+</sup>

Switch Current (I<sub>S</sub>, Continuous 1 Channel) ..... 20mA

Switch Current (I<sub>S</sub>, Surge 1 Channel, 1ms duration, 10% duty cycle) ..... 35mA

Lead Temperature (soldering, 10 seconds) ..... +300°C

Storage Temperature ..... -65°C to +150°C

Continuous Power Dissipation ..... T<sub>A</sub>=+70°C

16 lead CERDIP(derate 10.0mW/°C above +70°C) ..... 800mW

20 lead LCC (derate 9.1mW/°C above +70°C) ..... 727mW

Junction Temperature T<sub>J</sub> ..... +150°C

Thermal Resistance, Junction to Case, ΘJC:

Case Outline 16 lead CERDIP ..... 50°C/W

Case Outline 20 lead LCC ..... 20°C/W

Thermal Resistance, Junction to Ambient, ΘJA:

Case Outline 16 lead CERDIP ..... 100°C/W

Case Outline 20 lead LCC ..... 110°C/W

### Recommended Operating Conditions

Ambient Operating Range (T<sub>A</sub>) ..... -55°C to +125°C

Positive Supply Voltage (V<sup>+</sup>) ..... +15V

Negative Supply Voltage (V<sup>-</sup>) ..... -15V

V<sub>AL</sub> (max) ..... 0.8V

V<sub>AH</sub> (min) ..... 2.4V

NOTE 1: Do not apply voltages higher than V<sup>+</sup> and V<sup>-</sup> to any other terminal, especially when V<sup>-</sup>=V<sup>+</sup>=0V. All other pins should be 0V.

NOTE 2: The digital control inputs are diode protected; however damage may occur on unconnected units under high energy electrostatic fields. Keep unused units in conduction foam at all times.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TABLE 1. ELECTRICAL TESTS: DUAL SUPPLIES**

TEST	Symbol	CONDITIONS -55 °C <=T <sub>A</sub> <= +125°C V <sup>+</sup> =+15V, V <sup>-</sup> =-15V, GND=0V Unless otherwise specified	Group A Subgroup	Device type	Limits Min	Limits Max	Units
<b>ANALOG SWITCH</b>							
Drain-Source On Resistance	r <sub>DS(ON)</sub>	I <sub>S</sub> =1.0mA, V <sub>S</sub> =±10V Switch condition ON	1 2,3	All	300 450		Ω
Source-Off Leakage Current	I <sub>S(OFF)</sub>	V <sub>D</sub> =+10V V <sub>S</sub> =-10V V <sub>D</sub> =-10V V <sub>S</sub> =+10V, Enable Low. Switch condition OFF.	1 2,3	All		±0.5 ±50	nA
Drain-Off Leakage Current	I <sub>D(OFF)</sub>	V <sub>S</sub> =+10V, V <sub>D</sub> =-10V. V <sub>S</sub> =-10V, V <sub>D</sub> =+10V. Enable Low. Switch condition OFF.	1 2,3	01,03		±5 ±250	nA
			1 2,3	02		±3 ±125	
Channel-On Leakage Current I <sub>D(ON)</sub> -I <sub>S</sub>	I <sub>D(ON)</sub>	V <sub>S</sub> =+10V, Switch condition ON.	1 2,3	01,03		±5.5 ±300	nA
			1 2,3	02		±3.5 ±175	
<b>DIGITAL CONTROL</b>							
Address-Input Threshold (Low)	V <sub>INL</sub>		1,2,3	All		0.8	V
Address-Input Threshold (High)	V <sub>INH</sub>		1,2,3	All	2.4		V
Input Logic Current	I <sub>INL</sub> or I <sub>INH</sub>		1 2,3	All		10 30	μA
<b>POWER SUPPLY</b>							
Power Supply Range	V <sub>OP</sub>	For Continuous Operation NOTE 3		All	±4.5	±18	V
Positive Supply Current	I <sup>+</sup>	Digital Inputs=0V. Switch Conditions OFF.	1 2,3	All		0.1 0.2	mA
Negative Supply Current	I <sup>-</sup>	Digital Inputs=0V. Switch Conditions OFF.	1 2,3	All		0.1 0.2	mA
Positive Supply Current	I <sup>+</sup>	Digital Inputs=5V. Switch Conditions ON.	1 2,3	All		0.3 0.5	mA
Negative Supply Current	I <sup>-</sup>	Digital Inputs=5V. Switch Conditions ON.	1 2,3	All		0.1 0.2	mA
<b>DYNAMIC</b>							
Switching Time of Multiplexers	t <sub>TRANS</sub>	V <sub>IN</sub> =0V to 5V Switch Conditions OFF.	9 10,11	All		1000 1500	ns
Enable Turn-On Time	t <sub>ON</sub>	V <sub>EN</sub> =0V to 5V Switch Conditions ON.	9 10,11	All		1.5 2.0	μs
Enable Turn-Off Time	t <sub>OFF(EN)</sub>	V <sub>EN</sub> =0V to 5V Switch Conditions OFF.	9 10,11	All		1.0 1.5	μs

NOTE 3: Guaranteed but not tested at 25°C. Electrical characteristics will change when power supplies other than ±15V are used.

	<b>pkg</b>	<b>ORDERING INFORMATION:</b>	<b>pkg</b>	
01	16 CDIP	MX7501SQ/883B	20 LCC	MX7501SE/883B
02	16 CDIP	MX7502SQ/883B	20 LCC	MX7502SE/883B
03	16 CDIP	MX7503SQ/883B	20 LCC	MX7503SE/883B

**TRUTH TABLE**

**TERMINAL CONNECTION**

<b>A2</b>	<b>A1</b>	<b>A0</b>	<b>EN</b>	<b>MX7501 ON SWITCH</b>	<b>TERMINAL NUMBER</b>	<b>01/03 MX7501/03</b>	<b>01/03 MX7501/03</b>	<b>02 MX7502</b>	<b>02 MX7502</b>
X	X	X	0	None		J16	20LCC	J16	20LCC
0	0	0	1	1	1	A1	NC	A1	NC
0	0	1	1	2	2	GND	A1	GND	A1
0	1	0	1	3	3	EN	GND	EN	GND
0	1	1	1	4	4	A2	EN	OUT5-8	EN
1	0	0	1	5	5	S8	A2	S8	OUT5-8
1	0	1	1	6	6	S7	NC	S7	NC
1	1	0	1	7	7	S6	S8	S6	S8
1	1	1	1	8	8	S5	S7	S5	S7
					9	S4	S6	S4	S6
				<b>MX7502</b>	10	S3	S5	S3	S5
<b>A1</b>	<b>A0</b>	<b>EN</b>	<b>ON SWITCH</b>		11	S2	NC	S2	NC
X	X	0	None		12	OUT	S4	OUT1-4	S4
0	0	1	1 & 5		13	S1	S3	S1	S3
0	1	1	2 & 6		14	V+	S2	V+	S2
1	0	1	3 & 7		15	V-	OUT	V-	OUT1-4
1	1	1	4 & 8		16	A0	NC	A0	NC
					17		S1		S1
				<b>MX7503</b>	18		V+		V+
<b>A2</b>	<b>A1</b>	<b>A0</b>	<b>EN</b>	<b>ON SWITCH</b>	19		V-		V-
X	X	X	1	None	20		A0		A0
0	0	0	0	1					
0	0	1	0	2					
0	1	0	0	3					
0	1	1	0	4					
1	0	0	0	5					
1	0	1	0	6					
1	1	0	0	7					
1	1	1	0	8					

## **QUALITY ASSURANCE**

Sampling and inspection procedures shall be in accordance with MIL-Prf-38535, Appendix A as specified in Mil-Std-883.

Screening shall be in accordance with Method 5004 of Mil-Std-883. Burn-in test Method 1015:

1. Test Condition, A, B, C, or D.
2. TA = +125°C minimum.
3. Interim and final electrical test requirements shall be specified in Table 2.

Quality conformance inspection shall be in accordance with Method 5005 of Mil-Std-883, including Groups A, B, C, and D inspection.

Group A inspection:

1. Tests as specified in Table 2.
2. Selected subgroups in Table 1, Method 5005 of Mil-Std-883 shall be omitted.

Group C and D inspections:

- a. End-point electrical parameters shall be specified in Table 1.
- b. Steady-state life test, Method 1005 of Mil-Std-883:
  1. Test condition A, B, C, D.
  2. TA = +125°C, minimum.
  3. Test duration, 1000 hours, except as permitted by Method 1005 of Mil-Std-883.

**TABLE 2. ELECTRICAL TEST REQUIREMENTS**

Mil-Std-883 Test Requirements	Subgroups per Method 5005, Table 1
Interim Electric Parameters Method 5004	1
Final Electrical Parameters Method 5005	1*, 2, 3, 9
Group A Test Requirements Method 5005	1, 2, 3, 9, 10, 11
Group C and D End-Point Electrical Parameters Method 5005	1

\* PDA applies to Subgroup 1 only.